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Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: <http://www.renesas.com>

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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MOS FIELD EFFECT TRANSISTORS
2SK2365/2SK2366

SWITCHING
N-CHANNEL POWER MOS FET
INDUSTRIAL USE

Phase-out/Discontinued

DESCRIPTION

The 2SK2365, 2SK2365-Z/2SK2366, 2SK2366-Z is N-Channel MOS Field Effect Transistor designed for high voltage switching applications.

FEATURES

- Low On-Resistance
2SK2365: $R_{DS(on)} = 0.5 \Omega$ ($V_{GS} = 10 V, I_D = 5.0 A$)
2SK2366: $R_{DS(on)} = 0.6 \Omega$ ($V_{GS} = 10 V, I_D = 5.0 A$)
- Low C_{iss} $C_{iss} = 1\ 600\ pF$ TYP.
- High Avalanche Capability Ratings
- Isolate TO-220 Package

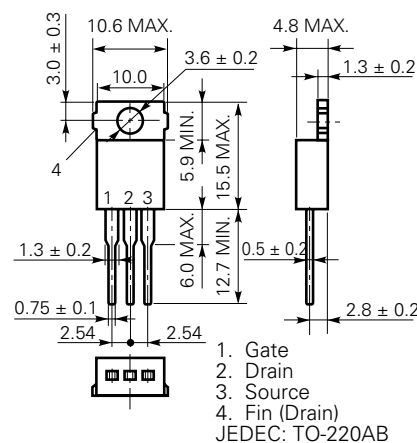
ABSOLUTE MAXIMUM RATINGS ($T_A = 25\ ^\circ C$)

Drain to Source Voltage (2SK2365/2SK2366)	V_{DSS}	450/500	V
Gate to Source Voltage	V_{GSS}	± 30	V
Drain Current (DC)	$I_{D(DC)}$	± 10	A
Drain Current (pulse)*	$I_{D(pulse)}$	± 40	A
Total Power Dissipation ($T_c = 25\ ^\circ C$)	P_{T1}	75	W
Total Power Dissipation ($T_A = 25\ ^\circ C$)	P_{T2}	1.5	W
Channel Temperature	T_{ch}	150	$^\circ C$
Storage Temperature	T_{stg}	-55 to +150	$^\circ C$
Single Avalanche Current**	I_{AS}	10	A
Single Avalanche Energy**	E_{AS}	143	mJ

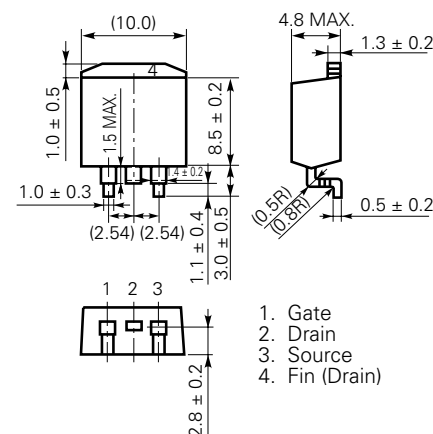
* $PW \leq 10\ \mu s$, Duty Cycle $\leq 1\ %$

** Starting $T_{ch} = 25\ ^\circ C$, $R_G = 25\ \Omega$, $V_{GS} = 20\ V \rightarrow 0$

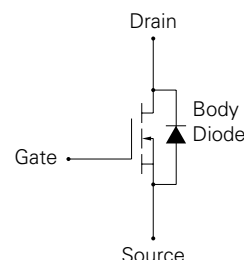
PACKAGE DIMENSIONS
(in millimeters)



MP-25 (TO-220)



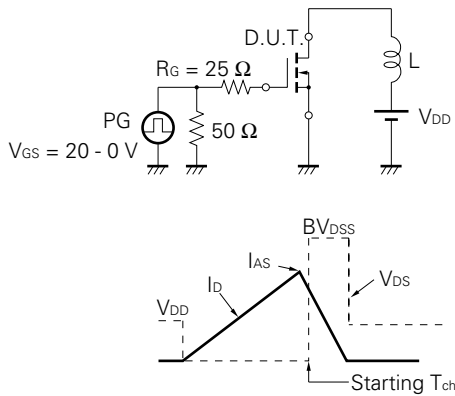
MP-25Z (SURFACE MOUNT TYPE)



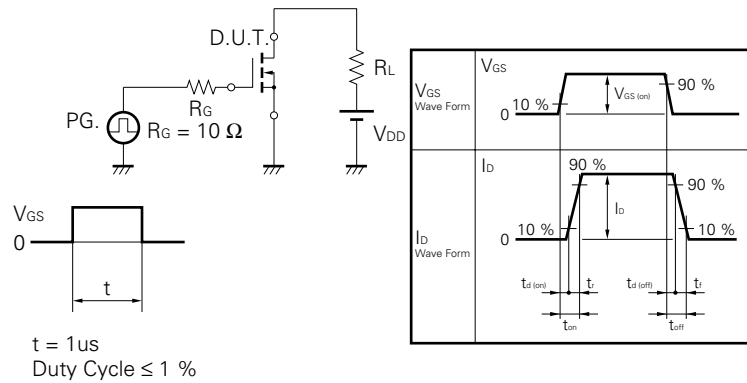
ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain to Source On-State Resistance	R _{DS(on)}		0.4	0.5	Ω	V _{GS} = 10 V 2SK2365
			0.5	0.6		I _D = 5.0 A 2SK2366
Gate to Source Cutoff Voltage	V _{GS(off)}	2.5		3.5	V	V _{DS} = 10 V, I _D = 1 mA
Forward Transfer Admittance	y _{fs}	4.0			S	V _{DS} = 10 V, I _D = 5.0 A
Drain Leakage Current	I _{DSS}			100	μA	V _{DS} = V _{DSS} , V _{GS} = 0
Gate to Source Leakage Current	I _{GSS}			±100	nA	V _{GS} = ±30 V, V _{DS} = 0
Input Capacitance	C _{iss}		1 600		pF	V _{DS} = 10 V
Output Capacitance	C _{oss}		310		pF	V _{GS} = 0
Reverse Transfer Capacitance	C _{rss}		30		pF	f = 1 MHz
Turn-On Delay Time	t _{d(on)}		30		ns	I _D = 5.0 A
Rise Time	t _r		20		ns	V _{GS} = 10 V
Turn-Off Delay Time	t _{d(off)}		80		ns	V _{DD} = 150 V
Fall Time	t _f		20		ns	R _G = 10 Ω R _L = 30 Ω
Total Gate Charge	Q _G		42		nC	I _D = 10 A
Gate to Source Charge	Q _{GS}		10		nC	V _{DD} = 400 V
Gate to Drain Charge	Q _{GD}		20		nC	V _{GS} = 10 V
Body Diode Forward Voltage	V _{F(S-D)}		1.0		V	I _F = 10 A, V _{GS} = 0
Reverse Recovery Time	t _{rr}		350		ns	I _F = 10 A, V _{GS} = 0
Reverse Recovery Charge	Q _{rr}		1.5		μC	di/dt = 50 A/μs

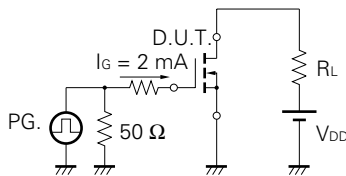
Test Circuit 1 Avalanche Capability



Test Circuit 2 Switching Time

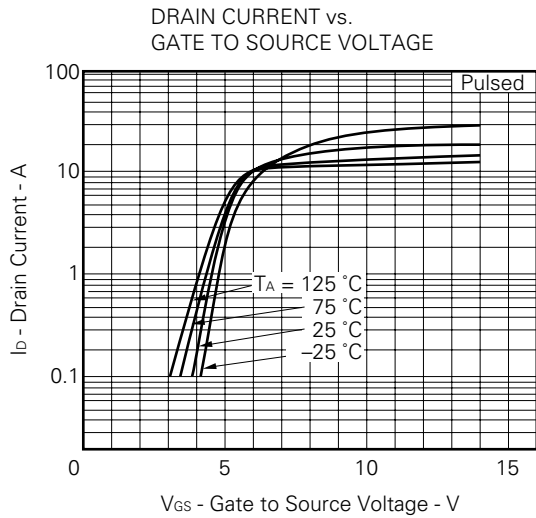
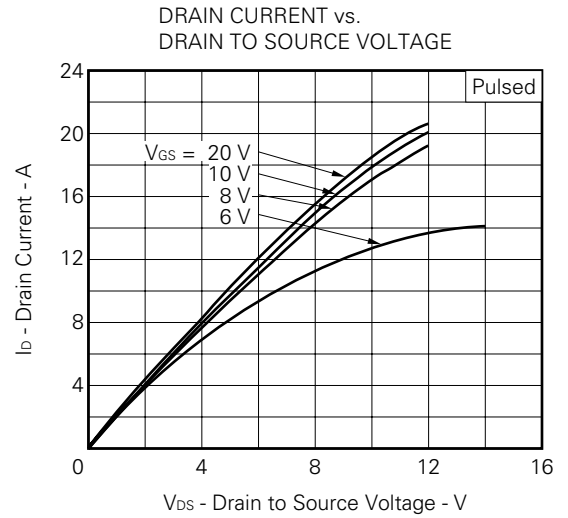
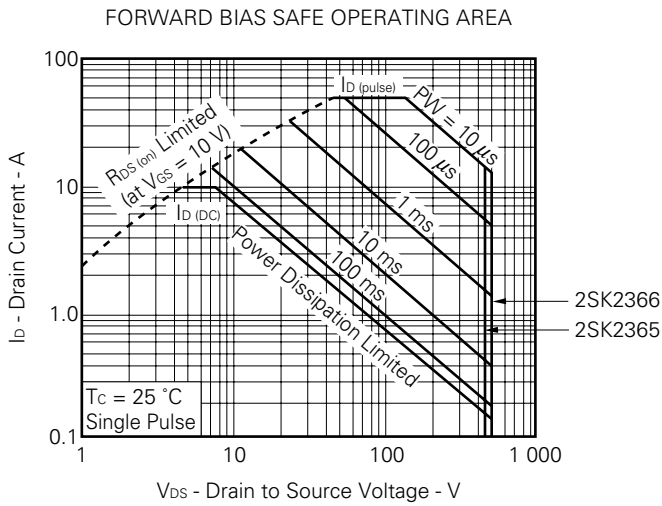
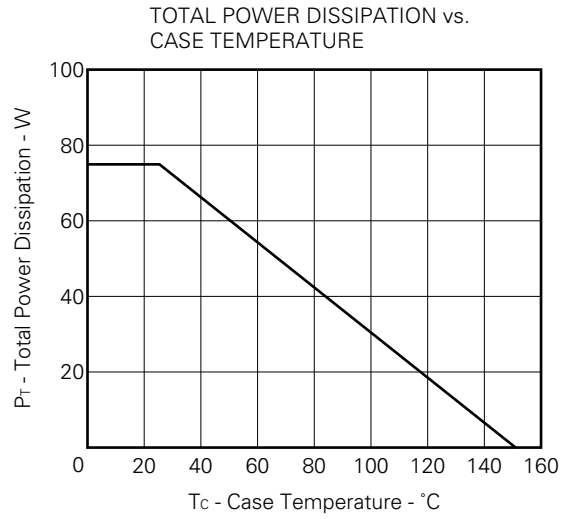
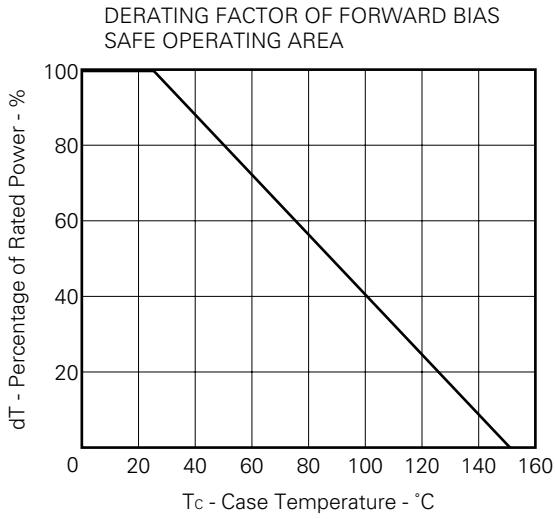


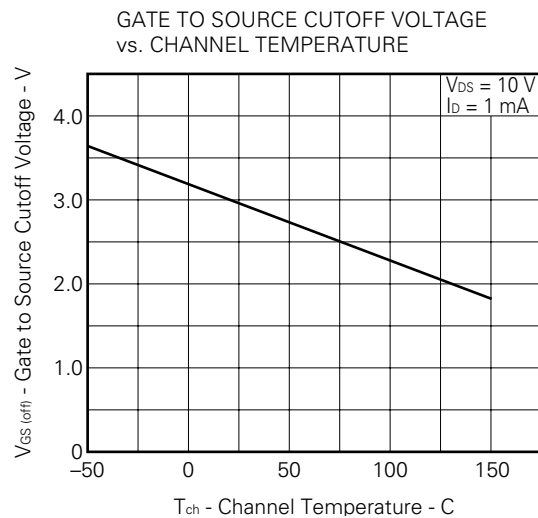
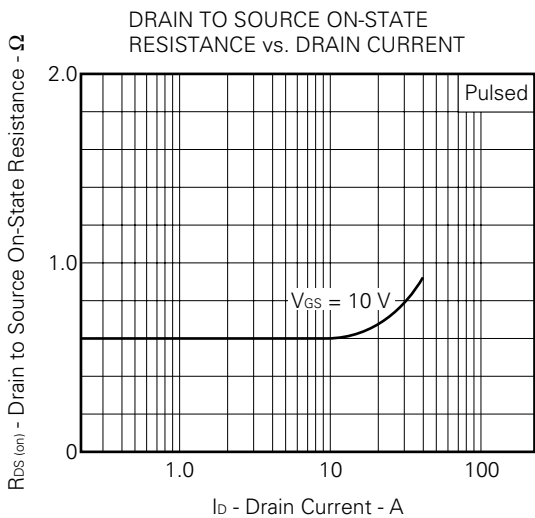
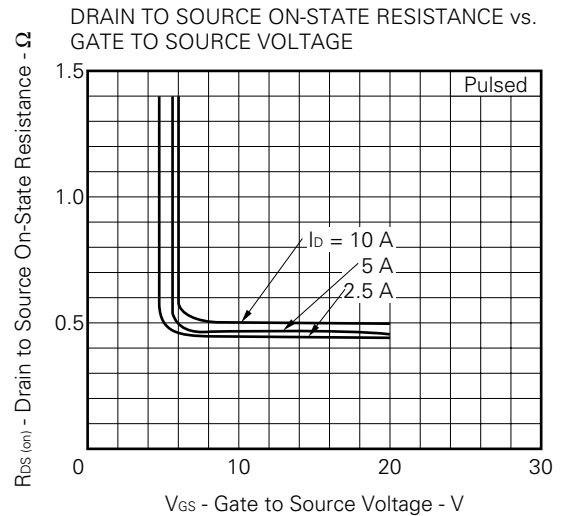
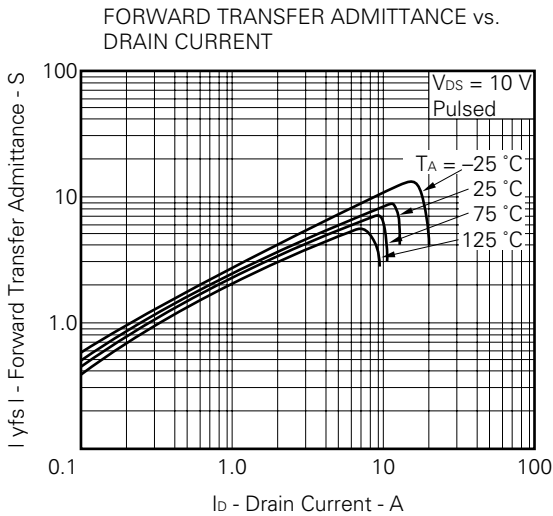
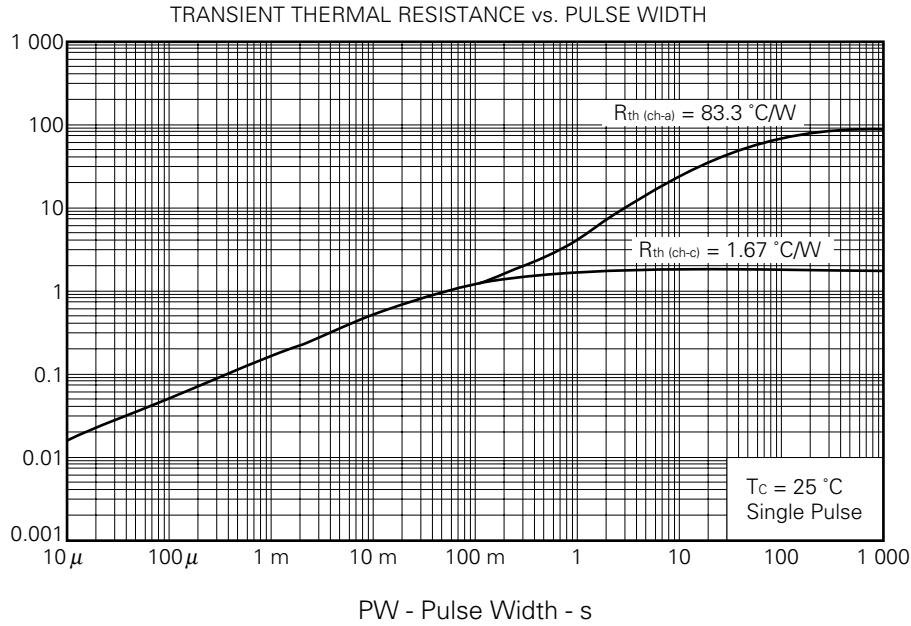
Test Circuit 3 Gate Charge

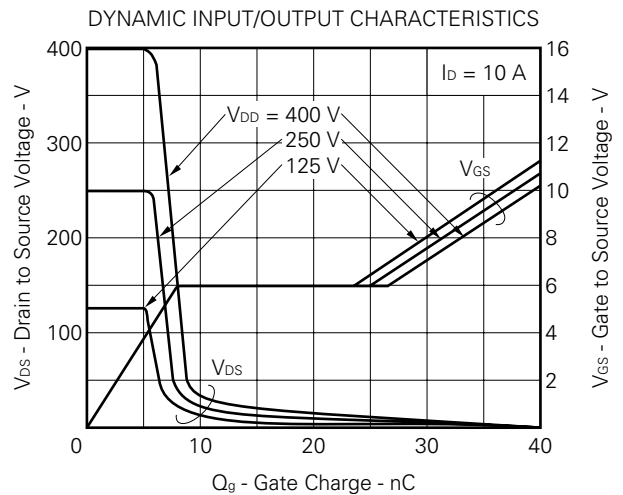
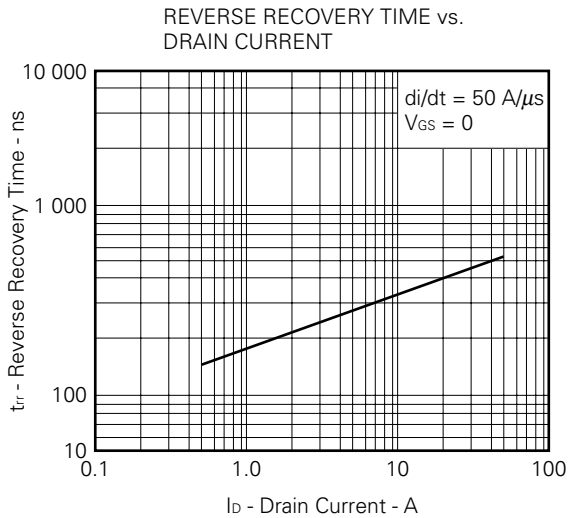
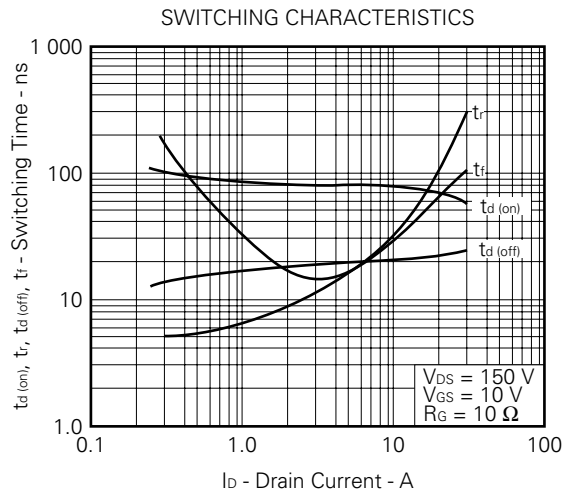
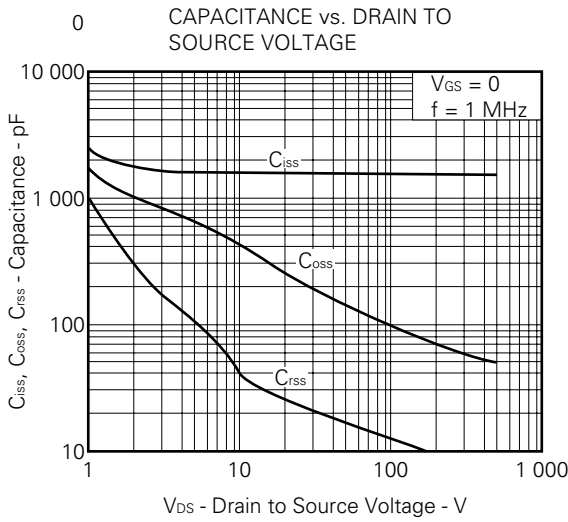
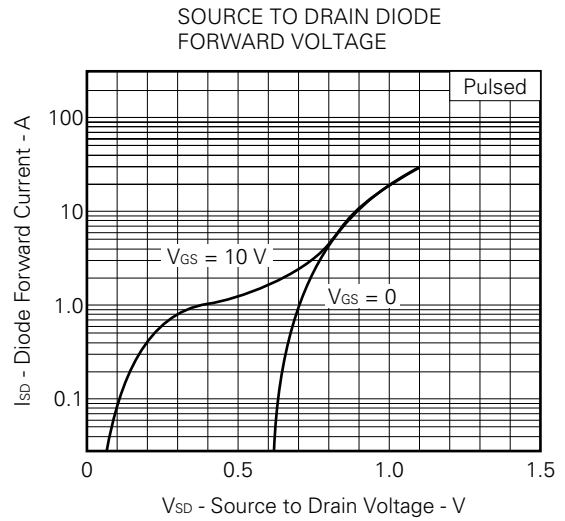
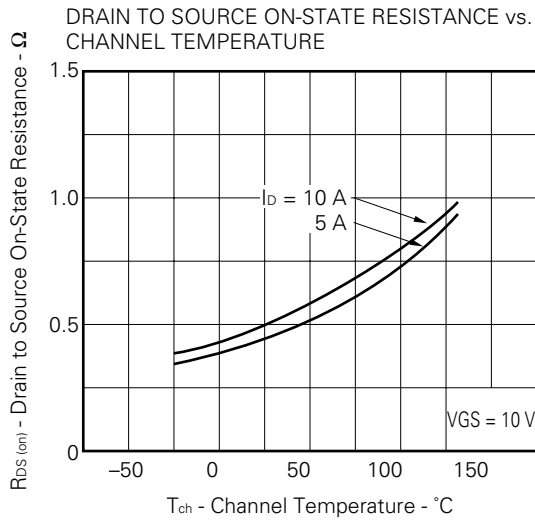


The application circuits and their parameters are for references only and are not intended for use in actual design-in's.

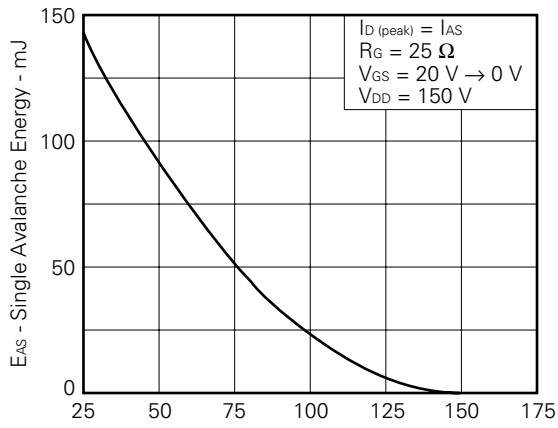
TYPICAL CHARACTERISTICS (T_A = 25 °C)



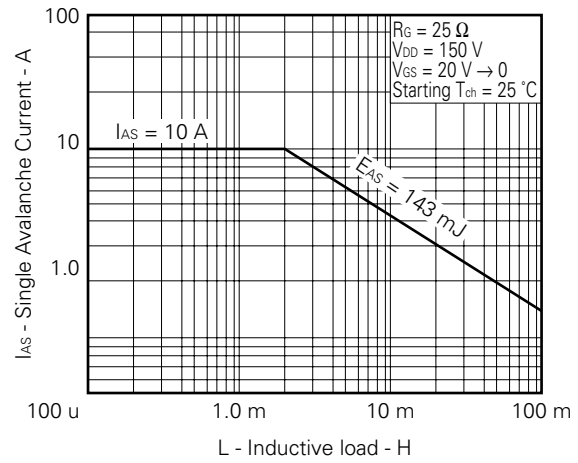




SINGLE AVALANCHE ENERGY vs. STARTING CHANNEL TEMPERATURE



SINGLE AVALANCHE CURRENT vs. INDUCTIVE LOAD



REFERENCE

Document Name	Document No.
NEC semiconductor device reliability/quality control system.	TEI-1202
Quality grade on NEC semiconductor devices.	IEI-1209
Semiconductor device mounting technology manual.	IEI-1207
Semiconductor device package manual.	IEI-1213
Guide to quality assurance for semiconductor devices.	MEI-1202
Semiconductor selection guide.	MF-1134
Power MOS FET features and application switching power supply.	TEA-1034
Application circuits using Power MOS FET.	TEA-1035
Safe operating area of Power MOS FET.	TEA-1037

The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device is actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

[MEMO]

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